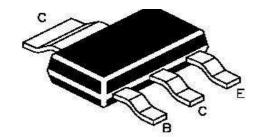




An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company

### NPN SILICON PLANAR EPITAXIAL TRANSISTOR



PZTA44

SOT-223 Formed SMD Package

## **High Voltage Transistor**

#### **ABSOLUTE MAXIMUM RATINGS**

DESCRIPTION	SYMBOL	VALUE	UNITS
Collector Base Voltage	V <sub>CBO</sub>	500	V
Collector Emitter Voltage	V <sub>CEO</sub>	400	V
Emitter Base Voltage	V <sub>EBO</sub>	6.0	V
Collector Current (DC)	I <sub>C</sub>	300	mA
Collector Current Peak	I <sub>CM</sub>	300	mA
Base Current Peak	I <sub>BM</sub>	100	mA
Power Dissipation upto T <sub>amb</sub> =25°C	*P <sub>D</sub>	1.35	W
Storage Temperature	T <sub>stg</sub>	- 65 to +150	ōC
Junction Temperature	T <sub>j</sub>	150	°C
Operating Ambient Temperature	T <sub>amb</sub>	- 65 to +150	ōC

### THERMAL RESISTANCE

From junction to ambient	*R <sub>th (j-a)</sub>	91	K/W
From junction to soldering point	R <sub>th (j-s)</sub>	10	K/W

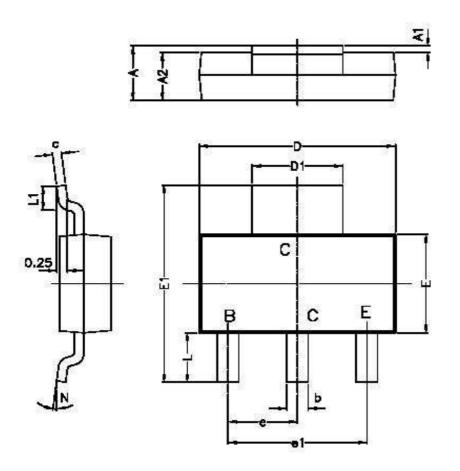
<sup>\*</sup> Device Mounted on a printed circuit board, single sided copper, tinplated, mounting pad for collector 1 cm<sup>2</sup>.

# ABSOLUTE MAXIMUM RATINGS (T<sub>amb</sub>=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
Collector Cut Off Current	I <sub>CBO</sub>	$V_{CB}$ =400V, $I_{E}$ =0			100	nA
		$V_{CB}=400V, I_{E}=0, T_{j}=150^{\circ}C$			10	μΑ
Emitter Cut Off Current	I <sub>EBO</sub>	$V_{EB}=4V$ , $I_{C}=0$			100	nA
DC Current Gain	h <sub>FE</sub>	I <sub>C</sub> =1mA, V <sub>CE</sub> =10V	40			
		$I_{C}=10$ mA, $V_{CE}=10$ V	50		200	
		$^*I_C=50$ mA, $V_{CE}=10$ V	45			
		$^*I_C = 100 \text{mA}, V_{CE} = 10 \text{V}$	40			
Collector Emitter Saturation Voltage	V <sub>CE (sat)</sub>	I <sub>C</sub> =1mA, I <sub>B</sub> =0.1mA			0.40	V
		I <sub>C</sub> =10mA, I <sub>B</sub> =1mA			0.50	V
		*I <sub>C</sub> =50mA, I <sub>B</sub> =5mA			0.75	V
Base Emitter Saturation Voltage	V <sub>BE (sat)</sub>	*I <sub>C</sub> =10mA, I <sub>B</sub> =1mA			0.85	V
Collector Capacitance	C <sub>c</sub>	V <sub>CB</sub> =20V, f=1MHz			7.0	pF
Emitter Capacitance	C <sub>e</sub>	V <sub>EB</sub> =0.5V, f=1MHz			180	рF
Transition Frequency	f <sub>T</sub>	I <sub>C</sub> =10mA, V <sub>CE</sub> =10V,f=100MHz	20			MHz

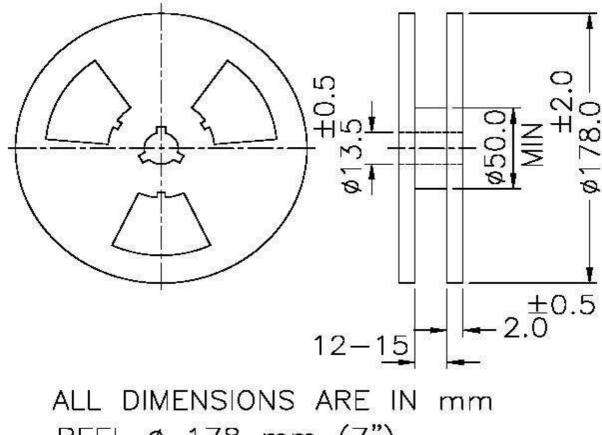
Pulse test tp  $\leq$ 300  $\mu$ s;  $\delta \leq$  0.02

# SOT-223 Formed SMD Package



DIM	MIN.	MAX.		
Α	1.520	1.800		
A1	0.020	0.100		
A2	1.500	1,700		
b	0.610	0.810		
С	0.250	0.350		
D	6.300	6.700		
D1	2.900	3.100		
E	3.300	3.700		
E1	6.700	7.300		
е	2.300	TYP		
e1	4.500	4.700		
2 25	1.760	TYP		
L1	0.900	1000		
N	0.	10"		

ALL DIMENSIONS ARE IN mm



ALL DIMENSIONS ARE IN mm REEL Ø 178 mm (7") 1000 Pcs / REEL

Customer Notes PZTA44

SOT-223 Formed SMD Package

# **Component Disposal Instructions**

- 1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
- 2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

#### **Disclaimer**

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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